



Peltier Supercooling with Isosceles Current Pulses: A Response Surface Perspective

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Using a pulsed electrical current enables a temporary state in which a Peltier element achieves temperatures below that obtained with a steady current. This is referred to as supercooling. Supercooling is followed by a period of superheating during which Peltier heat transfer is diminished and the surface temperatures increases. Most studies have found that the duration of superheating is longer than the duration of supercooling. As a result, the current pulse generates a net heating instead of enhanced cooling. There are limited studies that have shown the possibility of net cooling during a current pulse. The objective of this paper is to discuss the operating conditions for which net cooling is possible and maximized. The interaction between pulse duration and pulse height using isosceles shaped current pulses on net cooling was investigated using response surfaces generated using electrical-thermal analogies in SPICE. Pulse duration ranged from 0.1 to 10.0 seconds and pulse height ranging from 1.01 to 6.0 times steady current. Response surfaces were used to map a variety of performance factors; including the transient time to achieve a minimum temperature, the pulse cooling enhancement, transient penalty and transient advantage. The optimal combination of pulse duration and pulse height was identified. © The Author(s) 2017. Published by ECS. This is an open access article distributed under the terms of the Creative Commons Attribution 4.0 License (CC BY, <http://creativecommons.org/licenses/by/4.0/>), which permits unrestricted reuse of the work in any medium, provided the original work is properly cited. [DOI: 10.1149/2.0061703jss] All rights reserved.



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The cooling requirements for electronic devices has and continues to increase in response to higher power densities and smaller packaging.¹ Peltier devices offer a convenient method of ‘pumping’ heat. Peltier coolers are solid state heat pumps that directly convert electric current to a temperature difference and heat flux. Imposing a temperature difference will induce a current flow. The operating principle utilized is the thermoelectric effect.

Advantages of utilizing thermoelectrics for thermal management include heating and cooling from the same device, precise temperature control within 0.01°C,² ability to cool to temperatures below ambient, COP greater than one when using the device for heating, site specific thermal management rather than cooling the entire enclosure, no moving parts, high reliability, silent operation, operation in any orientation, no fluorocarbon usage and high cooling power density.

These devices have many commercial thermal management applications including electronics and CPU cooling applications.³ Thermoelectric air conditioners maintain enclosure temperatures for many different industries like hazardous environment, telecommunications, military, laboratory, and outdoor kiosk.⁴ Home and office products include small refrigerators,⁵ mattresses⁶ and office chairs.⁷ These devices are also used in medical products that provide thermal therapy.⁸ Automotive applications include temperature controlled seating,⁹ cup holders and mini in-vehicle refrigerators.¹⁰ Recent research has focused on use of these devices for hybrid vehicle battery thermal management systems^{11,12} and zonal heating and cooling of passenger vehicles.¹³

Equation 1 is the governing differential equation¹⁴ for a single free-standing thermoelement under transient conditions. The assumptions are one-dimensional heat transfer and constant material properties. Here I is the electrical current flowing parallel to the dimension L and perpendicular to the area A . The distribution of temperature at any location x and time t is described as $T(x, t)$. In this equation ρ is the electrical resistivity, κ is the thermal conductivity and a is the thermal diffusivity.

$$\frac{\partial^2 T(x, t)}{\partial x^2} + \frac{I^2 \rho}{A^2 \kappa} = \frac{1}{a} \frac{\partial T(x, t)}{\partial t} \quad [1]$$

Typical boundary conditions applied to Equation 1 are constant temperature on the hot side and constant flux from Peltier cooling on the cold side. Here $\alpha = \alpha_p - \alpha_n$ and I is current.

$$T(x = L, t) = T_h \quad [2]$$

$$\left. \frac{\partial T(x, t)}{\partial x} \right|_{x=0} = \frac{\alpha I T_c(t)}{A \kappa} \quad [3]$$

Analytical approximations and numerical solutions have been developed for this set of equations.¹⁴⁻¹⁶

In contrast to transient conditions, steady state cooling power at T_c for n couples is expressed as

$$\dot{Q}_c = n \left[\alpha T_c I - \left(\frac{1}{2} \right) I^2 R - K \Delta T \right] \quad [4]$$

This equation is made up of a Peltier cooling term, a Joule heating term and a Fourier conduction term. Here α is the Seebeck coefficient of the couple $\alpha = \alpha_p - \alpha_n$ [V/K], T_c is the temperature of the cold side of each thermoelement, and I is the electric current through the couple. R is the electrical resistance of the couple in units of ohms. K is the thermal conductance [W/K] of the couple and ΔT is the temperature difference between T_c and T_h . The resistance R is dependent on the thermoelement material electrical resistivity ρ and the thermal conductance K is dependent on the thermoelement material thermal conductivity k . Increasing α while decreasing ρ and k lead to improved cooling power, \dot{Q}_c . Thermoelectric materials are likewise characterized with the figure of merit, $Z = \alpha^2 / \rho k$. Here α is the Seebeck coefficient and can be α_p or α_n . Increasing Z leads to improved performance.

Two values of electric current are of interest for this work. I_{\max} is the electrical current that sustains the maximum temperature difference between T_h and T_c . I_{opt} is the electrical current that sustains maximum \dot{Q}_c . I_{\max} ¹⁷ and I_{opt} ¹⁸ are characterized as follows:

$$I_{\max} = \frac{\alpha}{R} \left[\left(T_h + \frac{1}{Z} \right)^2 - T_h^2 \right]^{1/2} - \frac{1}{Z} \quad [5]$$

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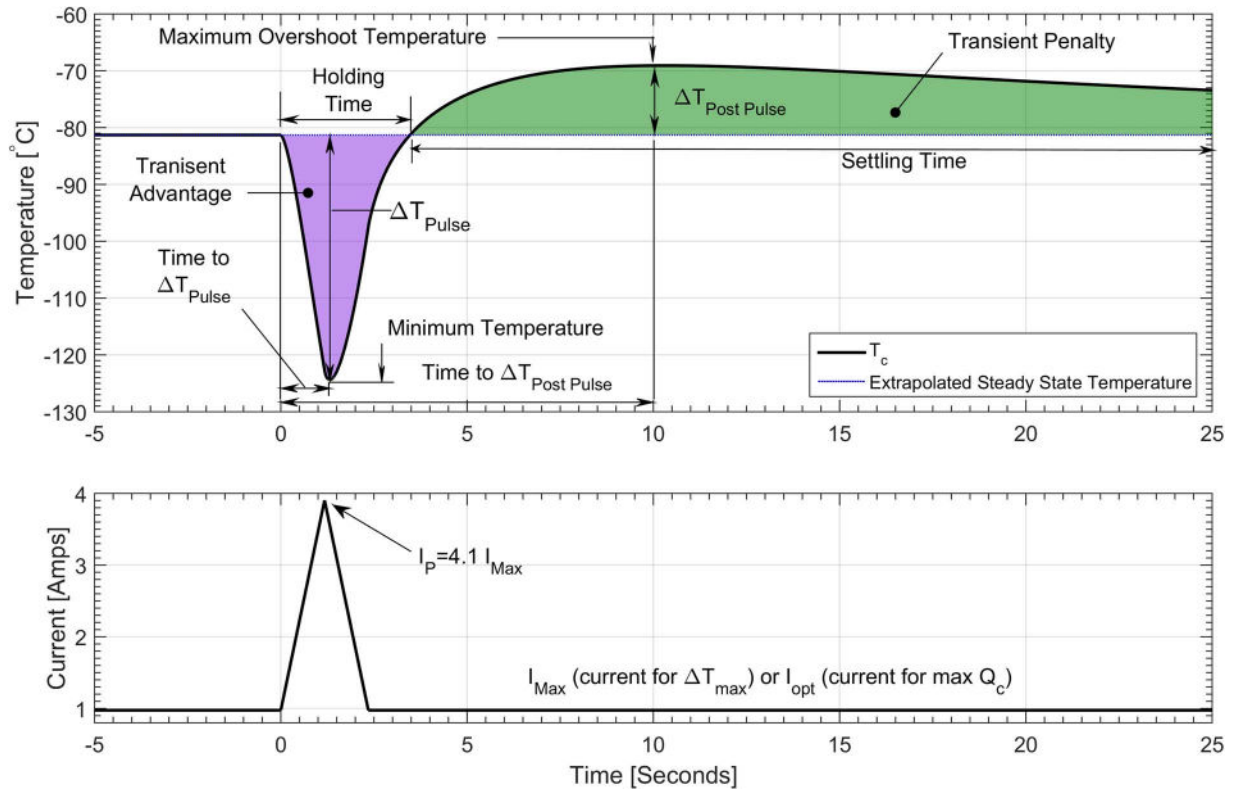


Figure 1. Performance factors and temperature response following a triangle current pulse.

$$I_{\text{opt}} = \frac{\alpha T_h}{R} \quad [6]$$

Here $\alpha = \alpha_p - \alpha_n$ [V/K] is the Seebeck coefficient of the couple and R is the electrical resistance of the couple.

In contrast to steady state electrical current operation described above, research of pulsed supercooling operation consists of investigating the effects of current pulses on device performance. These pulses are applied while the device is operating at steady current.

Figure 1 illustrates the effect of such a current pulse while operating at I_{max} steady current. Upon application of a current pulse, an instantaneous lower temperature (supercooling) is achieved. T_c decreases to a minimum and then rises above the steady state (I_{max}) value to a maximum. Then T_c decreases exponentially to the steady-state value. This instant lower temperature achieved followed by an overshoot is due to different time constants of Peltier cooling and Joule heating. Increased Peltier cooling is an instantaneous and interfacial effect that only takes place at the cold junction of each couple. Joule heating takes place instantly throughout the volume of each thermoelement. The volumetric Joule heat has a slower time constant and is delayed from reaching T_c by diffusion throughout the thermoelement.

The following nomenclature, described in Figure 1 will be used for this work: ΔT_{pulse} ,¹⁵ $\Delta T_{\text{postpulse}}$,¹⁵ holding time,¹⁹ time to minimum temperature,²⁰ time to maximum temperature overshoot,²¹ settling time,²² transient advantage,¹⁹ transient penalty,¹⁹ net transient advantage,²¹ and pulse cooling enhancement.¹⁹

Variables that affect pulsed Peltier cooling include: thermoelement length,¹⁵ current pulse amplitude^{15,19} pulse duration,¹⁹ pulse shape,^{14,16,19,22-27} time between pulses,²⁸ thermoelectric figure of merit,¹⁵ thermoelement thermal diffusivity¹⁵, thermoelement shape²⁹⁻³¹ and the number of stages of a multi-stage thermoelectric cooler.³² Of these variables, there are only two that can be varied to change the operating conditions for any given pulse shape. These two are pulse height, $P = I_{\text{pulse}}/I_{\text{max}}$ ¹⁵ and pulse duration.

Manno et al.¹⁹ first defined the metrics transient advantage and transient penalty. For the constant pulse height and pulse duration simulated, Manno et al.¹⁹ found for an Isosceles shaped pulse, the transient advantage was larger than the transient penalty. This research for the first time quantified that it is possible to have a net cooling advantage with transient operation. Since the operating parameters chosen for this study may have been incidental, the possibility of another combination of pulse height and pulse duration where the transient advantage is even larger than transient penalty is likely to exist.

The range of operating conditions for which transient advantage is larger than transient penalty for an Isosceles shaped current pulse has been identified herein. Response surfaces of net transient advantage²¹ as a function of pulse height and pulse duration over a comprehensive range for each variable are developed. Furthermore the effects to other characteristic transient parameters shown in Figure 1 have been examined, with a surface generated for each parameter over the same comprehensive range of pulse height and pulse duration. Finally the effects of starting the pulses from two different steady state currents (I_{max} and I_{opt}) are discussed.

This research is an important step toward achieving the iNEMI road map goal of finding cost effective and more effective solutions by maximizing performance of a given device and understanding the tradeoffs of improved performance with other characteristic transient parameters. Increased transient performance would allow a device to be downsized at lower cost or improve performance at the same cost.

Materials and Methods

The object of the study was a single freestanding thermocouple as shown in Figure 2. The model was originally developed by Mitrani et al.¹⁴ The height of the thermoelement was 5 mm with a cross sectional area was 1 mm².¹⁴ Material properties of Bi_2Te_3 were used. For the generated surfaces, $\sigma = 1.0482e^5 \Omega^{-1} m^{-1}$,

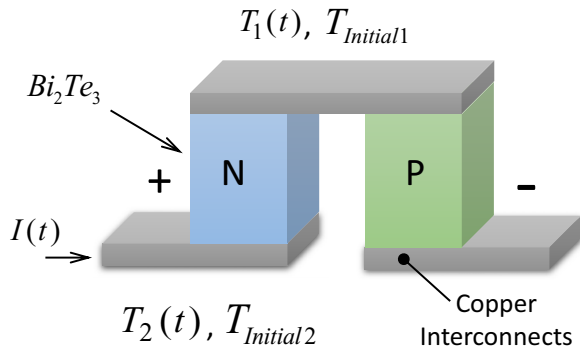


Figure 2. Thermocouple.

$\kappa = 1.5718 \text{ W m}^{-1} \text{ K}^{-1}$, $\alpha = 1.9700e^{-4} \text{ V K}^{-1}$, $\rho = 7530 \text{ kg m}^{-3}$, $c_p = 544 \text{ J kg}^{-1} \text{ K}^{-1}$.³³ These material properties were found by interpolating between data given at multiple temperatures. This interpolation used a sixth order polynomial curve fit to 308.15 K. The thermoelectric figure of merit was, $ZT_h = 0.89$. T_h was maintained at 308.15 K. The steady state currents used prior to pulsing were $I_{max} = 0.9748$ amps and $I_{opt} = 1.272$ amps. The independent variables were pulse duration, which ranged from 0.1–10 seconds and pulse height $P = I_p/I_{max}$ or $P = I_p/I_{opt}$ which ranged from 1.01 to 6 times the steady current. The pulse shape was an Isosceles triangle.

Differential equations derived for transient thermoelectric operation are unable to be solved in closed form,¹⁴ therefore other solution methods are used. Snyder et al.¹⁵ derived a 1D linear approximation model of a couple that was capable of modeling the supercooling portion of a transient pulse event. Three dimensional models that use ANSYS³⁴ or Comsol³⁵ have been used to model the entire event but these models are computationally complex. For this work, a transient model was developed in SPICE. SPICE was chosen because it was expandable for future studies in terms of adding mass, boundary conditions and thermal interface resistances. Furthermore the software is free, accurate and fast. The speed was beneficial due to the large number of simulations required to generate the response surfaces.

In the 1970's, SPICE (Simulation Program with Integrated Circuit Emphasis) was developed³⁶ for solving integrated circuit problems. SPICE solvers can also be used to solve electrical-thermal analogy problems. SPICE analogy models have been developed to simulate thermoelectric coolers. Chavez et al.³⁷ designed a steady state SPICE model of thermoelectric cooler that was accurate to within 0.5°C . Lin³⁸ created a steady state SPICE model designed to accept inputs from thermoelectric cooler manufacture data sheets with very good accuracy. Lineykin and Ben-Yaakov¹⁸ developed a semi-lumped/semi-distributed mass transient SPICE model. Mitrani et al.¹⁴ devised a 1D distributed mass model suitable for simulating transient pulsed cooling using SPICE. In this model, there was good agreement with other models¹⁴ and this model is the basis of the work herein. Sullivan et al.³⁹ compared his SPICE model results with a finite volume Fluent model. There was good agreement of results between the two models, however the SPICE model was up to 430% faster.

The Mitrani et al.¹⁴ model utilized for this study is a scalable 1D model of a thermoelectric couple and is made up of both a thermal and electric portion. Each portion consists of networked electrical components and is solved using software that contains a SPICE algorithm. For the thermal model, electrical-thermal analogies were used (shown in Table I) to decide the input values for each electrical components. The electrical-thermal analogy portion and the pure electrical circuit portion are linked to capture the combined electrical and thermal nature of a device. The physics associated with the thermoelectric device including Peltier cooling, Peltier heating, Joule heating, thermal resistance, thermal capacitance, electrical resistance and Seebeck voltage. The model takes a distributed mass and heat generation approach and captures the time separation between the Peltier effect, Joule heating effect, the Seebeck effect and transient thermal conduction throughout

Table I. Thermal Electrical Analogies.

Thermal Quantity	Electrical Analogy
Temperature [K]	Voltage [V]
Absolute Zero [0 K]	Ground [0 V]
Thermal Energy Flow Rate, $\dot{Q} = \left(\frac{\Delta T}{R_{th}}\right)$ [W]	Current Flow, $I = \left(\frac{\Delta V}{R}\right)$ [A]
Thermal Energy, $Q = \left(\frac{\Delta T t}{R_{th}}\right)$ [J]	Charge, $C = \left(\frac{\Delta V t}{R}\right)$ [As]
Thermal Conductivity, $k \left[\left(\frac{\text{W}}{\text{mK}}\right)\right]$	Electrical Conductivity, $\sigma \left[\left(\frac{1}{\Omega\text{m}}\right)\right]$
Thermal Mass, $C_{th} \left[\left(\frac{\text{J}}{\text{K}}\right)\right]$	Electrical Capacitance, $C = \left(\frac{\Delta Q}{\Delta V}\right)$ [F]
Thermal Resistance, $R_{th} \left[\left(\frac{\text{K}}{\text{W}}\right)\right]$	Electrical Resistance, $R = \left(\frac{V}{I}\right)$ [Ω]

the thermoelement. The thermoelement is broken down into discrete parts that are analogous to finite elements. With this model, fifty finite elements are used.

In the thermal portion of the model, each finite element has mass, internal Joule heat generation and thermal resistance. Here, mass is analogous to a capacitor. Joule heat generation is analogous to current flow in a current source. Thermal resistance is analogous to electrical resistance. The Peltier effect is a heat flow and is analogous to current flow in a current source. Current out of a node simulates Peltier cooling and current into a node simulates Peltier heating. A diagram of the circuit analogy is available.¹⁴

The electrical model consists of a separate circuit on the same schematic as the thermal analogy model. Both of these models are solved simultaneously. The electrical model contains one current source. This is where the input electrical current for the model is defined. The electrical circuit also contains a voltage source and resistor for each finite element of the model. These voltage sources simulate the Seebeck voltage generated at each finite element in the thermal analogy model. The voltage sources are software linked to the thermal model and are dependent on the temperature difference across each finite element of the thermoelement model multiplied by the Seebeck coefficient. The resistors in the electrical model simulate the electrical resistance of each finite element of the thermoelement.

A voltage source is connected to the hot side of the device as a boundary condition. The voltage source in this model acts as a constant temperature thermal reservoir that maintains the hot side temperature.

The solve procedure for SPICE starts with the program forming a set of equations for each node of the circuit using Kirchhoff's current law (KCL). The matrix of equations is then solved by Gaussian elimination. When voltage sources are used in place of current sources, the voltage matrix is not known and therefore Gaussian elimination cannot be used. In this case, SPICE first uses a Norton equivalent circuit and then solves the matrix with Gaussian elimination. For circuits with nonlinear elements, the Newton-Raphson method is applied followed by Gaussian elimination. For transient simulations, SPICE utilizes numerical integration.⁴⁰

The modeling process is categorized into four main steps. The first step is the model build step. This is the step where the model is built with the SPICE software. The second step is the preprocessing step. Here, the inputs to the SPICE model are calculated and entered into the SPICE model. This includes all variables for all electrical components and the PWL (Piece-wise Linear) electrical current text file which dictates the electrical current profile used. The third step is running the SPICE model and exporting the data. This can be done manually or by using a third party automation software. The fourth step is post processing the exported data. A detailed explanation of this process is available.²¹

The response surfaces generated required 2025 combinations of pulse-height and pulse duration to be simulated. This means 2025 PWL electrical current profile files for each surface. Generating these PWL files manually as well as post processing would have been time

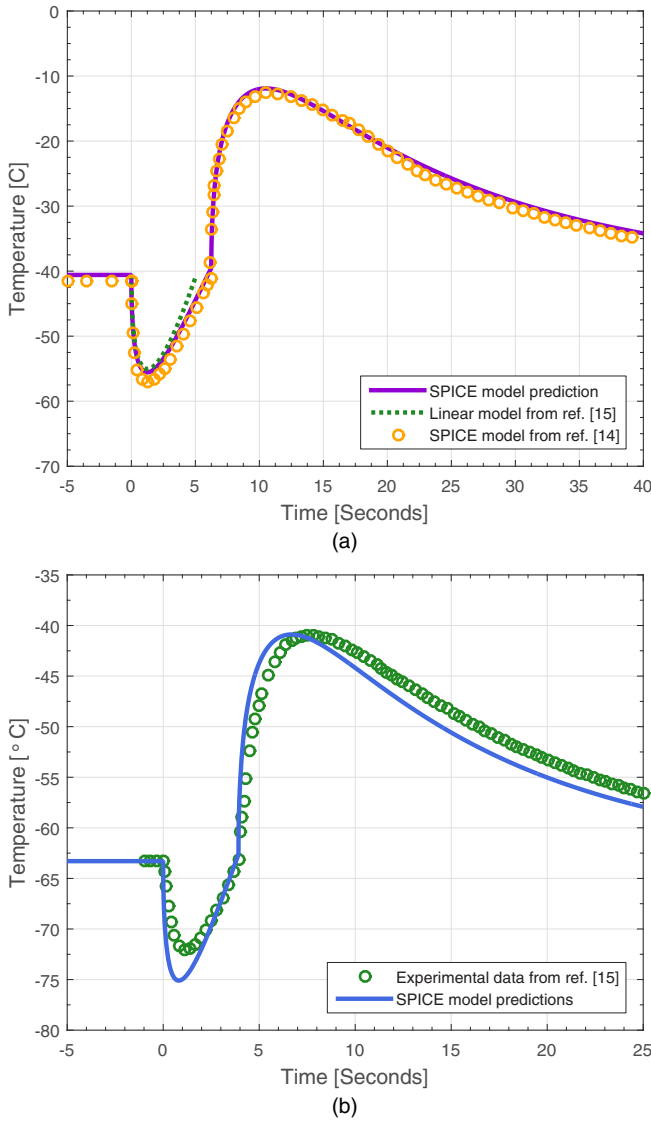


Figure 3. SPICE model validation (a) SPICE model prediction compared with other models (b) SPICE model prediction compared with experimental data.

prohibitive so the calculations and post processing of these files was automated using nested loops.

Model validation.—The SPICE model used herein was validated in two ways. The first method of validation was a comparison of the model predictions with other available models. The second method of validation was a comparison with the predictions of the model with experimental data.

The SPICE model is compared to the results from a linear model shown in Equation 7,¹⁵

$$\frac{T(x, t) - T_{ss}}{z(T_c)^2} = (P^2 - 1) \frac{at}{L^2} - (P - 1) \frac{\sqrt{at}}{L} e^{-x/\sqrt{at}} \quad [7]$$

where T_{ss} is the steady state temperature profile corresponding to ΔT_{max} , T_c is the temperature prior to the current pulse, $P = I_p/I_{max}$, a is the thermal diffusivity, and L is the length of the thermoelectric element parallel to current flow. There is good agreement between the SPICE model and this linear model with the same properties as shown in Figure 3a, though the linear model cannot capture the transient penalty region. A second model is also used as a comparison. This model, developed by Mitrani et al.,¹⁴ is also coded into SPICE. There are slight differences between the two SPICE models due to

uncertainty in material properties. The source for the temperature dependent material properties was reported by Mitrani et al.,¹⁴ but not the specific values used. The uncertainty lies in the interpolation between temperatures for the reported values.

To determine the exact properties used by Mitrani et al.,¹⁴ one would need to know the original temperature and the type of curve fitting that was used. To extract the material properties from the table for the model validation herein, constant temperature properties were used as determined at the steady state temperature $T_{ave} = (T_h + T_c)/2 = 266.15 K$. A second order curve fit was used for α , a first order for σ , and fourth order for κ . The properties and other input data used herein are $\kappa = 1.9045 e^{-4} V K^{-1}$, $\sigma = 1.1321 e^5 \Omega^{-1} m^{-1}$, $\kappa = 1.6468 W m^{-1} K^{-1}$, $\rho = 7530 kg m^{-3}$, $c_p = 544 J kg^{-1} K^{-1}$, $T_c = 232.15 K$, $\Delta T_{max} = T_h - T_c = 68 K$ at $\dot{Q}_c = 0$, $I_{max} = 0.977 A$, $I_p/I_{max} = 2.5$, Pulse duration = 6.245 sec, $L = 5 mm$, $A = 1 mm^2$. The source of the intrinsic thermoelement properties is a Melcor handbook⁴¹ that is no longer publicly available. The fitted equations for this material data as a function of temperature in K can be found below in Equations 8–10. These equations are valid from 225 K to 475 K.

$$\alpha(T) = -2.02518 e^{-9} T^2 + 1.42345 e^{-6} T - 4.49536 e^{-5} \frac{V}{K} \quad [8]$$

$$\rho(T) = 4.35357 e^{-8} T - 2.75414 e^{-6} \Omega m \quad [9]$$

$$\kappa(T) = 3.46200 e^{-10} T^4 - 4.88458 e^{-7} T^3 + 2.82165 e^{-4} T^2 - 7.65339 e^{-2} T + 9.50065 \frac{W}{m K} \quad [10]$$

The second method used to validate the model used herein was by comparison with experimental data in Figure 3b. Intrinsic material properties were provided in a paper subsequent to the experimental data.¹⁶ The properties and parameters provided were $\alpha = 2.35 e^{-4} V K^{-1}$, $\kappa = 1.2 w m^{-1} K^{-1}$, $\sigma = 5.1100 e^4 \Omega^{-1} m^{-1}$, $\rho c_p = 1.20e6 J m^{-3} K^{-1}$, $A = 1.0 e^{-6} m^2$, $L = 0.0058 m$, $T_c = 209.86 K$, $I_{max} = 0.675$ at $\dot{Q}_c = 0$, $\tau = 4 sec$, $I_p/I_{max} = 2.5$, $ZT_c = 0.51$ at $T_c = 229.85 K$. The intrinsic material properties could not be used to accurately reproduce the characteristic supercooling transient because the measurement location for the experimental results is not provided. The unavailable items were temperature dependent thermoelement properties, hot side thermal interface resistance to the heat sink, heat sink thermal resistance, cooling rate for an actively cooled heat sink and mass of the heat sink.

Instead of using intrinsic properties to reproduce the experimental data, effective properties were used. These effective properties can be calculated knowing the steady state parameters I_{max} , ΔT_{max} , T_h , Q_{max} , A , and L .¹⁷ The effective material properties take into account electrical and thermal contact resistances, steady state temperature dependence of the material and steady state convective and radiative losses. These properties are specific to the system and the provided intrinsic properties are specific to the thermoelement.

The process to find the effective properties was to first find the dimensional figure of merit, z . This was found from the provided zT_c and associated temperature. The dimensional figure of merit was lower than that found with the intrinsic properties. This was acceptable and expected because it was calculated with system level data and therefore represents an effective property that takes into account losses. Next $\Delta T_{max} = T_h - T_c = Z(T_c)^2/2$ ¹⁵ and T_h were determined. Q_{max} was not provided and can be calculated with $Q_{max} = \alpha^2 T_c^2 / 2R$ ³ where α is the Seebeck coefficient of the couple, $\alpha = \alpha_p - \alpha_n = (I_{max}/T_h - \Delta T_{max})R$ ¹⁷ where R is the electrical resistance of the couple. In the resulting equation, R could not be determined with effective properties. R was found iteratively when the output of the SPICE model converged as best as possible with the experimental data. The effective properties that were used to generate the SPICE model output in Figure 3b are $\alpha^* = 1.3077 e^{-4} V K^{-1}$, $\kappa^* = 1.0374 w m^{-1} K^{-1}$, $\sigma^* = 1.4265 e^5 \Omega^{-1} m^{-1}$.

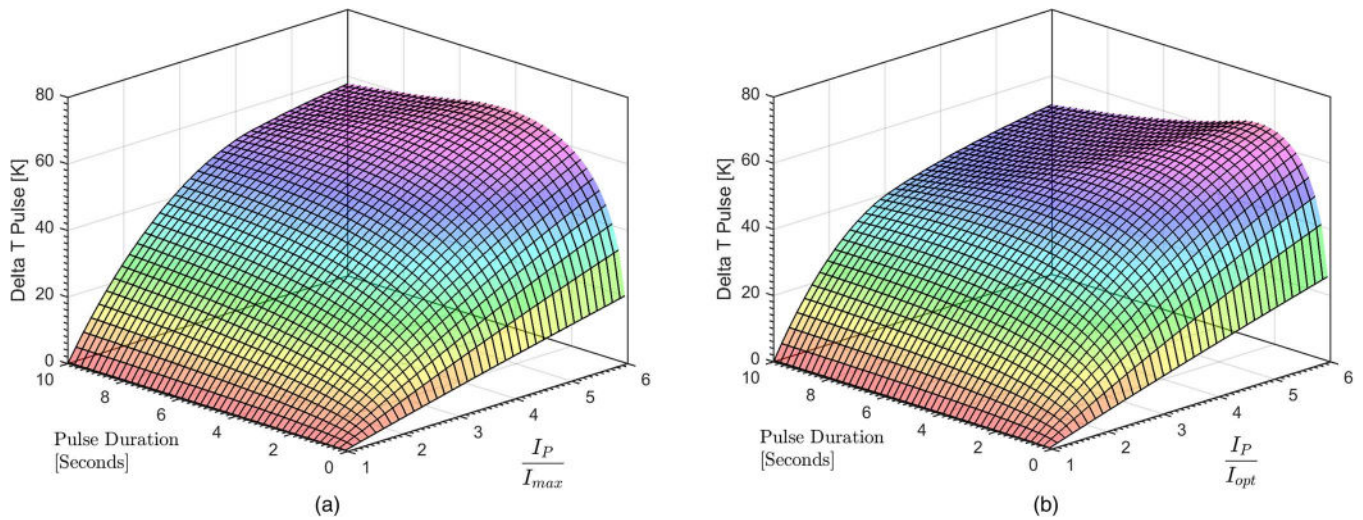


Figure 4. ΔT_{Pulse} (a) I_{max} (b) I_{opt} .

Currently the SPICE model used herein only simulates the thermoelements. The accuracy of the SPICE model could be improved when using intrinsic properties by taking into account temperature dependent thermoelement material properties as this has been shown to have a significant effect.³¹ Additional accuracy could be gained by adding thermal resistances of solder and copper, their masses, any thermal interface resistances¹⁷ between the copper and heat sinks, the thermal resistance of heat sinks as well as the heat sink mass. If the heat sink is actively cooled, the heat transfer from the heat sink should be included. Further improvements could be gained by modeling the Joule heat generated within the solder and copper as well as radiative and convective losses.²⁷ To produce a model that accurately reproduces the transient effect from experimental data with intrinsic properties, these items must be included and / or provided in the experimental technical paper that provides experimental data. To simplify reporting, sometimes, T_h is measured and reported vs. time and then imposed on the model.⁴² Additionally, it has been found²¹ that 1 to 5 significant figures should be used when reporting parameters in order to reproduce transient supercooling results to one decimal place accuracy. Since this number varies, 5 significant figures is recommended for communicating these parameters.

Response of Freestanding Couple to Pulsed Current

Response surfaces were created for each of the parameters that describe pulse cooling in Figure 1. The independent variables for the response surfaces are pulse duration and pulse height. All surfaces were generated using isosceles triangle shaped pulses. For each parameter, a surface was generated starting pulses from I_{max} and another surface generated starting from I_{opt} for comparison.

ΔT_{Pulse} .— ΔT_{Pulse} is the difference between the steady state T_c temperature and the minimum temperature achieved during the current pulse. This temperature difference is due to the difference in time constants between Joule heat and Peltier cooling.

In Figure 4, there is a clear maximum on both ΔT_{Pulse} surfaces. A clear trend is ΔT_{Pulse} is always higher with increasing I_P/I_{max} . It is also seen that in general ΔT_{Pulse} increases with longer pulse duration except for the highest I_P/I_{max} values where it decreases. This reduction in ΔT_{Pulse} is due to the triangular shape of the pulse and interaction between Peltier cooling and Joule heat. The longer the duration of the isosceles triangular pulse, the slower the ramp rate of current during the pulse. In the absence of Joule heat, the peak rate of heat removal at T_c would be achieved at the peak of the current pulse since Peltier cooling linearly increases with current. For longer pulses, this peak heat removal would occur later. Now adding Joule heat back in, the

time delayed Joule heat may reach T_c before the Peltier cooling peaks at maximum current. In this way, for longer pulses, peak ΔT_{Pulse} is reduced. This does not happen at lower I_P/I_{max} because Joule heat is dependent on the square of current.

Pulse cooling enhancement.—Pulse cooling enhancement is the ratio of ΔT_{Pulse} to ΔT_{max} . A pulse cooling enhancement of 0.4 means a 40% reduction in temperature from the pulse compared to I_{max} steady state operation. In Figure 5, a pulse cooling enhancement of 55% is seen with pulses starting from I_{max} and slightly less for I_{opt} of around 52%. The shape of this surface is the same as ΔT_{Pulse} because the same data is used for both surfaces. Value is added by presenting this data from two different perspectives. ΔT_{Pulse} is the perspective of absolute temperature and pulse cooling enhancement gives a normalized perspective that is useful when comparing between multiple independent experiments.

Time to minimum temperature.—Time to minimum temperature is the time at which ΔT_{Pulse} occurs. Time to minimum temperature in Figure 6 is the longest when pulse duration is maximum and I_P/I_{max} is minimum. Time to minimum temperature is the minimum with minimum pulse duration throughout the range of pulse-heights. The two surfaces of Figure 6 are very similar with exception of the area in the upper right hand corner where a transition occurs. In this area it appears that time to minimum temperature decreases nonlinearly with increasing I_P/I_{max} and decreases linearly with increases pulse duration. For shorter pulses, there is no non-linear reduction with I_P/I_{max} . The reason for this has to do with the time separation of Peltier cooling and Joule heat and the slope current vs. time. For shorter pulses, the pulse and minimum temperature occur before Joule heat has time reach T_c and slow down the decrease to minimum temperature. For longer pulses, the Joule heat reaches T_c before the Peltier cooling can peak at the apex of the triangular pulse. It takes much longer to reach the current apex for a long duration triangle.

Shorter pulses reach minimum temperature sooner because the peak current and thus peak Peltier cooling is reached faster due to the current pulse shape. If peak Peltier cooling is reached sooner, time to minimum temperature is shorter. There is a linear trend of decreasing time to minimum temperature with increased I_P/I_{max} at constant pulse duration at the lower end of pulse duration range. This happens because the heat removed from T_c in Joules is substantially proportional to the rate in watts at which it is removed. With higher I_P/I_{max} , the minimum temperatures get lower, however the cooling rate is faster than for lower I_P/I_{max} . This keeps the time to minimum temperature about the same throughout the range of I_P/I_{max} . The linear trend is more pronounced at short pulse durations because time

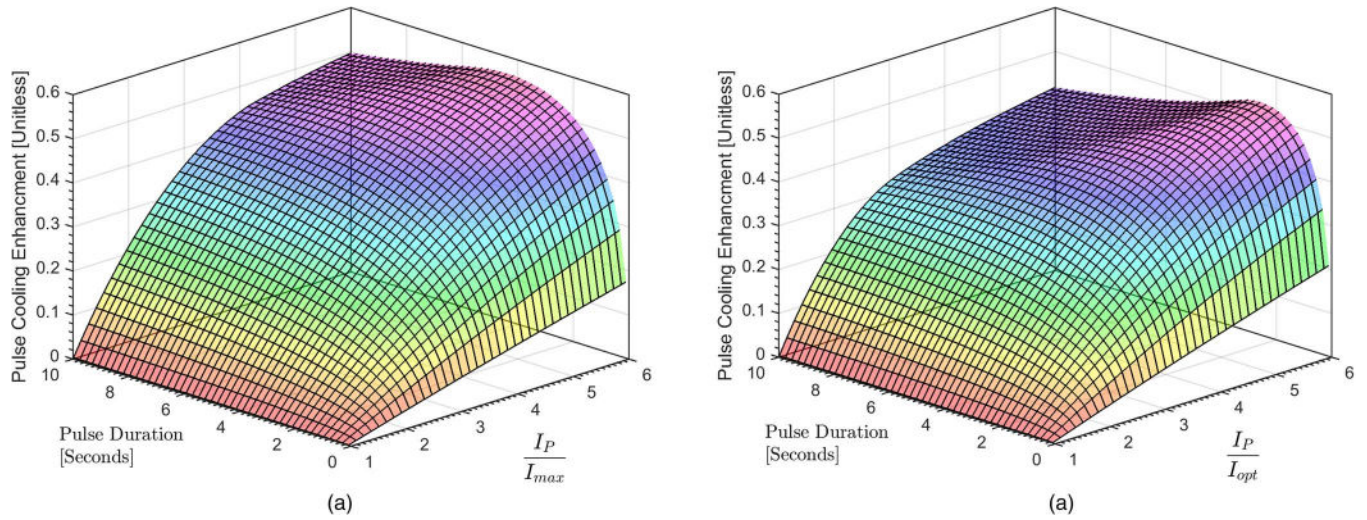


Figure 5. Pulse Cooling Enhancement (a) I_{max} (b) I_{opt} .

delayed Joule heat is less of a factor for short pulses. The pulses are complete before the Joule heat arrives.

The area of decreased time to minimum temperature in the upper right corner is larger for the I_{opt} current because of operation at a higher current. The effects are magnified due to more Joule heat.

Holding time.—Holding time is defined as the amount of time during a transient pulse event that T_c spends below steady state temperature. Figure 7 shows holding time is a linear function of pulse duration and a nonlinear function of I_P/I_{max} . Although not shown on Figure 7a for clarity, for I_{max} operation and I_P/I_{max} smaller than 1.146, holding time increases to approximately 300 to 400 seconds with pulse duration ranging from 0.1 to approximately 10 seconds. Peak holding time for I_{max} operation is much higher than that of I_{opt} operation.

The nonlinear decrease in holding time is due to an exponential amount of Joule heat relative to Peltier cooling. Peltier cooling increases linearly with increased current and Joule heat increases with the square of current. The increased heat reaching T_c reduces the time spent below steady current operation.

Transient advantage.—Transient advantage is the area of the supercooling portion of a transient pulse event. This metric is an aggregate

of both minimum temperature achieved and time spent below I_{max} steady state temperature which is also known as holding time. Transient advantage is illustrated by the purple shaded area in Figure 1. The peak transient advantage is the point that has the best combination of minimum temperature achieved and longest holding time.

From Figure 8 the effects of both pulse duration and I_P/I_{max} are nonlinear. The maximum transient advantage occurs at approximately $I_P/I_{max} = 4$ for both I_{max} and I_{opt} . Additional transient advantage may be gained with additional pulse duration that is beyond the independent variable limits studied here. The peak transient advantage is around 225Ks for I_{max} operation and around 175Ks for I_{opt} operation.

$\Delta T_{post\ pulse}$.— $\Delta T_{postpulse}$ is the magnitude of the delta between the maximum temperature achieved and the temperature achieved by steady state operation. In Figure 9, we see that $\Delta T_{postpulse}$ increases linearly with pulse duration and exponentially with I_P/I_{max} . For pulses starting from I_{max} operation, $\Delta T_{postpulse}$ was 150 K versus 300 K for pulses starting from I_{opt} when influenced by the same independent variables.

Temperature is a function of heat added in Joules to T_c . More heat added to T_c increases its temperature. Increasing I_P/I_{max} exponentially increases Joule heat added to T_c due to Joule heating being proportional to the square of current. The linear increase in $\Delta T_{postpulse}$ with

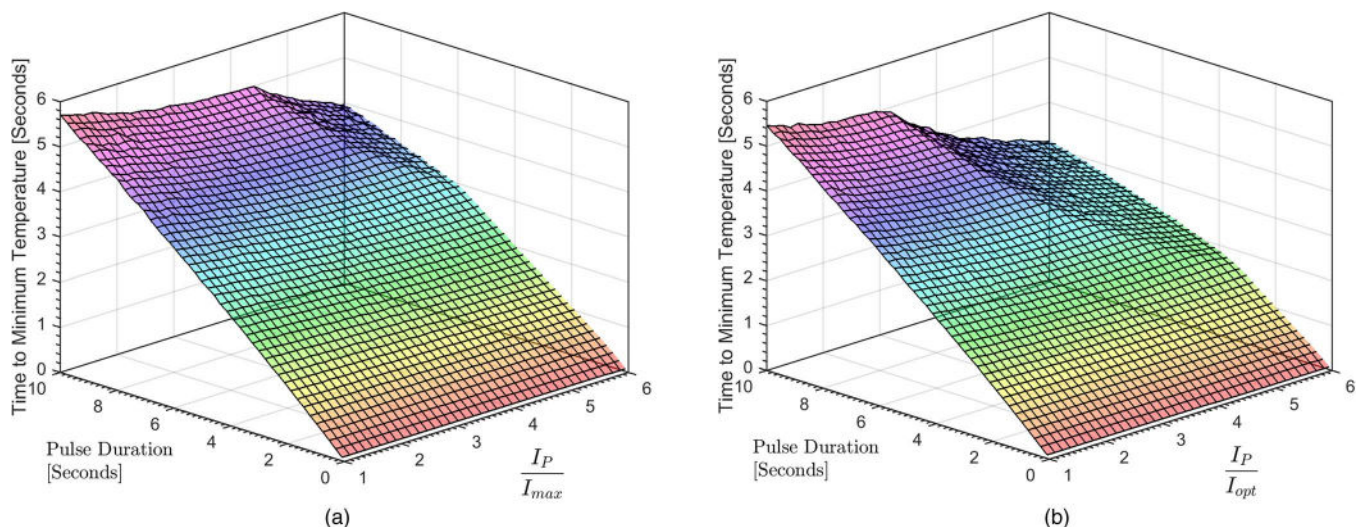


Figure 6. Time to Minimum Temperature (a) I_{max} (b) I_{opt} .

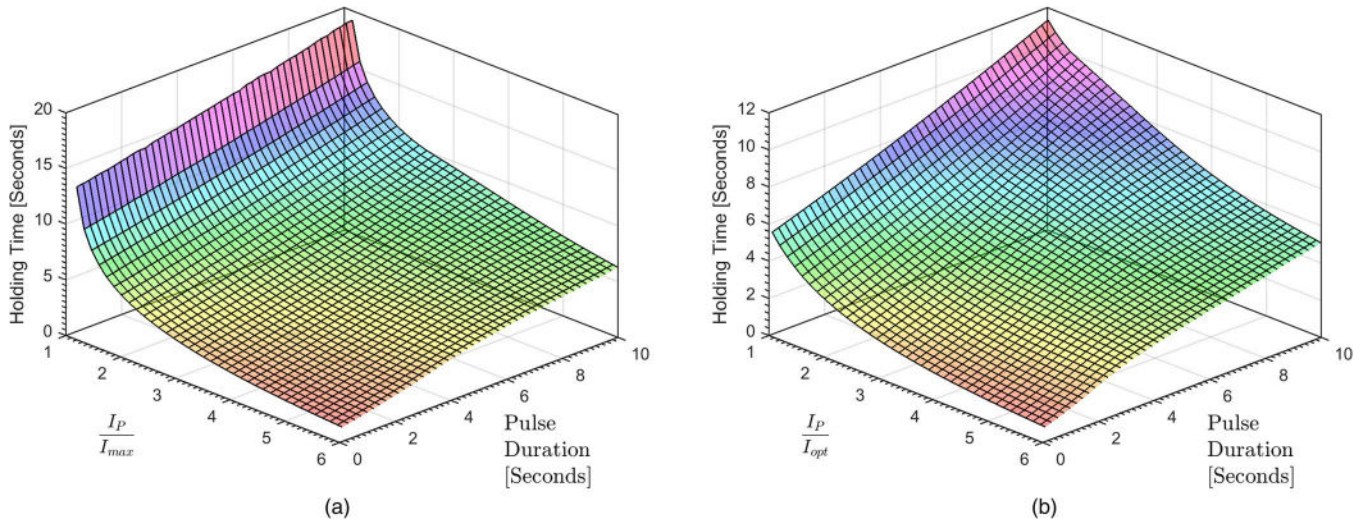


Figure 7. Holding Time (a) I_{max} (b) I_{opt} .

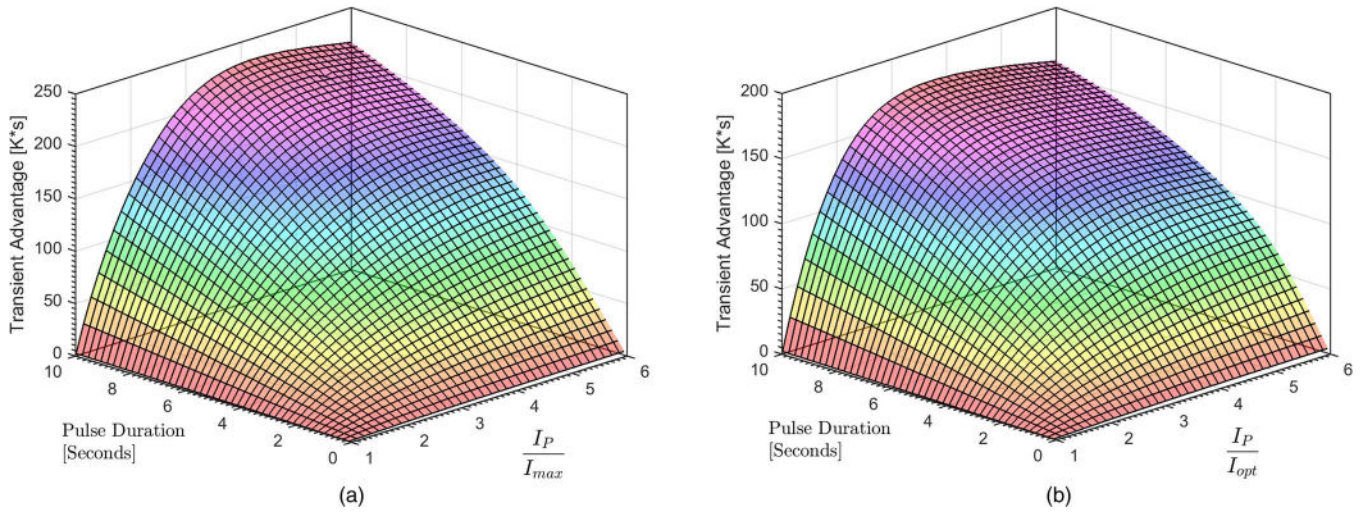


Figure 8. Transient Advantage (a) I_{max} (b) I_{opt} .

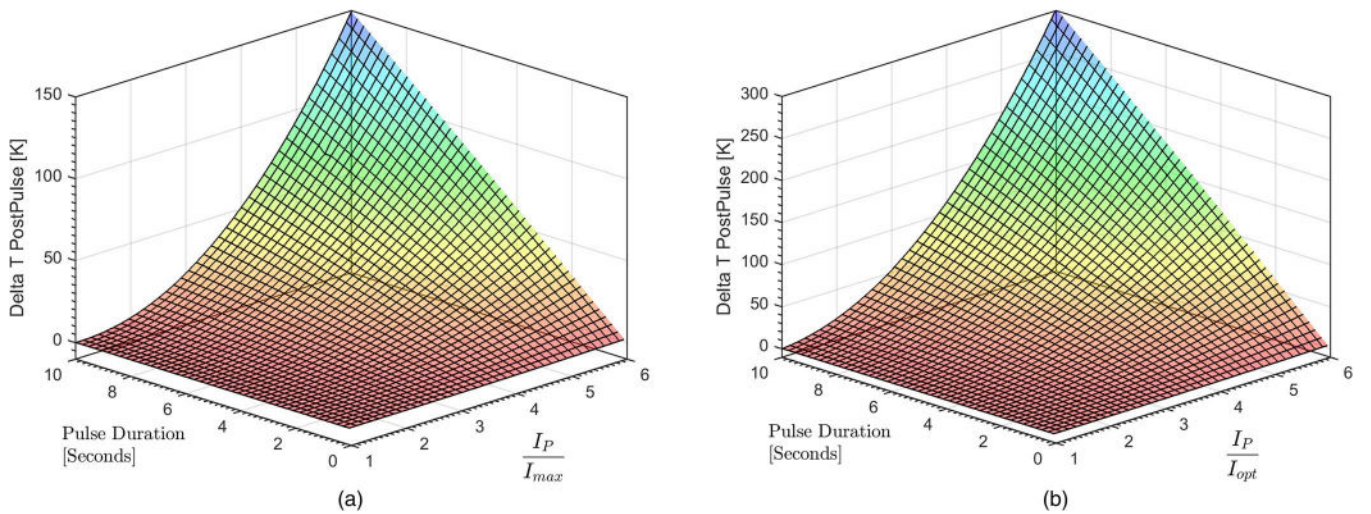


Figure 9. $\Delta T_{post\ pulse}$ (a) I_{max} (b) I_{opt} .

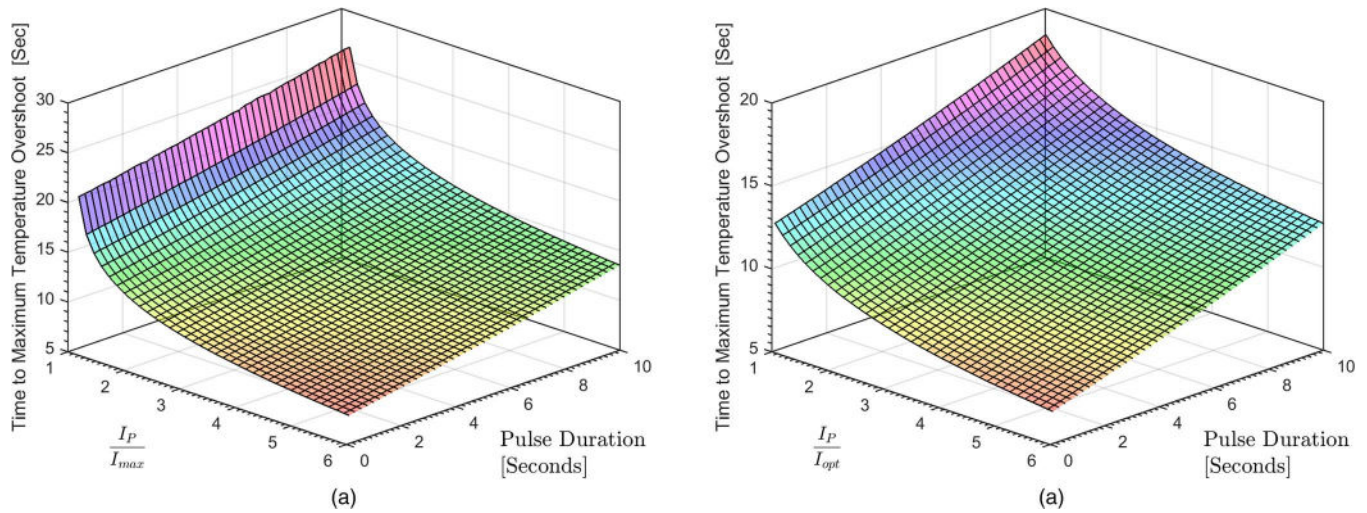


Figure 10. Time to Maximum Temperature (a) I_{max} (b) I_{opt} .

increased pulse duration is due to a linear increase in heat added to T_c . With the same I_p/I_{max} , the rate of Joule heat generation is the same from one pulse duration to the next, however the duration increases. The total heat addition is the power multiplied by the duration. This heat added is linearly proportional to pulse duration and thus we see the linear trend.

Time to maximum temperature overshoot.—Time to maximum temperature overshoot is the time to maximum temperature during the transient pulse event. This maximum temperature can occur after or during the pulse, depending on the pulse duration. In Figure 10 the time to maximum temperature overshoot is a linear function of pulse duration and a nonlinear function of I_p/I_{max} . The maximum time to maximum temperature occurs at maximum pulse duration and minimum I_p/I_{max} . The minimum time to maximum temperature overshoot occurs at the shortest pulse duration and largest I_p/I_{max} . For the same range of independent variables, the time to maximum temperature overshoot is longer starting from I_{max} than from I_{opt} .

Time delayed Joule heat is responsible for the maximum temperature overshoot. The time required to get to maximum temperature overshoot is highly dependent on the rate at which Joule heat is being generated and the time the maximum temperature overshoot begins. Higher I_p/I_{max} generates Joule heat at an exponential rate compared to Peltier cooling. This results in the nonlinear decrease in time to

minimum temperature at higher I_p/I_{max} . The linear decrease in time to minimum temperature with decreasing pulse duration is due to the linear reduction in heat in Joules added to T_c due to a linear reduction in duration for which that heat is generated. Since the overshoot cannot occur until after holding time, longer holding means a longer wait for maximum temperature overshoot. This longer wait is proportional to the increase in pulse duration.

Transient penalty.—Transient penalty is the area of the superheating portion of a transient pulse event. This metric is an aggregate of $\Delta T_{postpulse}$ and settling time. Transient penalty is illustrated by the green shaded area in Figure 1. In Figure 11, the transient penalty increases linearly with pulse duration and exponentially with I_p/I_{max} . Transient penalty approaches zero at very small pulse height and pulse duration.

At constant pulse duration and higher I_p/I_{max} , the rate of Joule heat generation is exponentially higher. $\Delta T_{postpulse}$ increases because more Joules of heat have been added to T_c . Heat is added at the same rate for a constant I_p/I_{max} however more pulse duration linearly adds heat in Joules to T_c . This is why the linear trend with pulse duration is seen.

Net transient advantage.—Net transient advantage is the difference between transient advantage and transient penalty. A positive

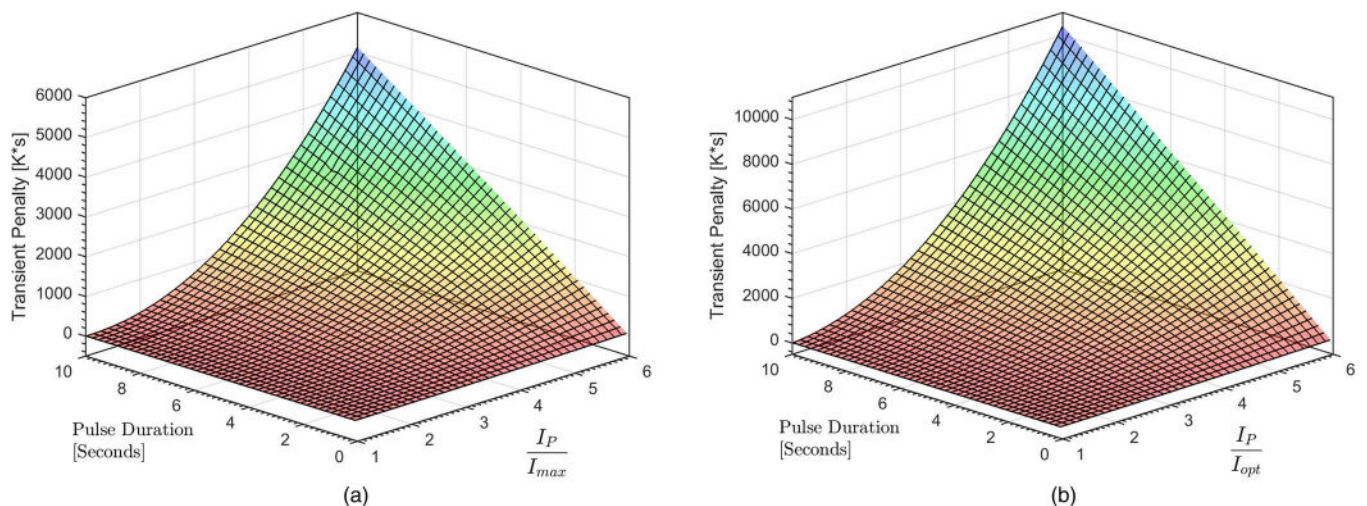


Figure 11. Transient Penalty (a) I_{max} (b) I_{opt} .

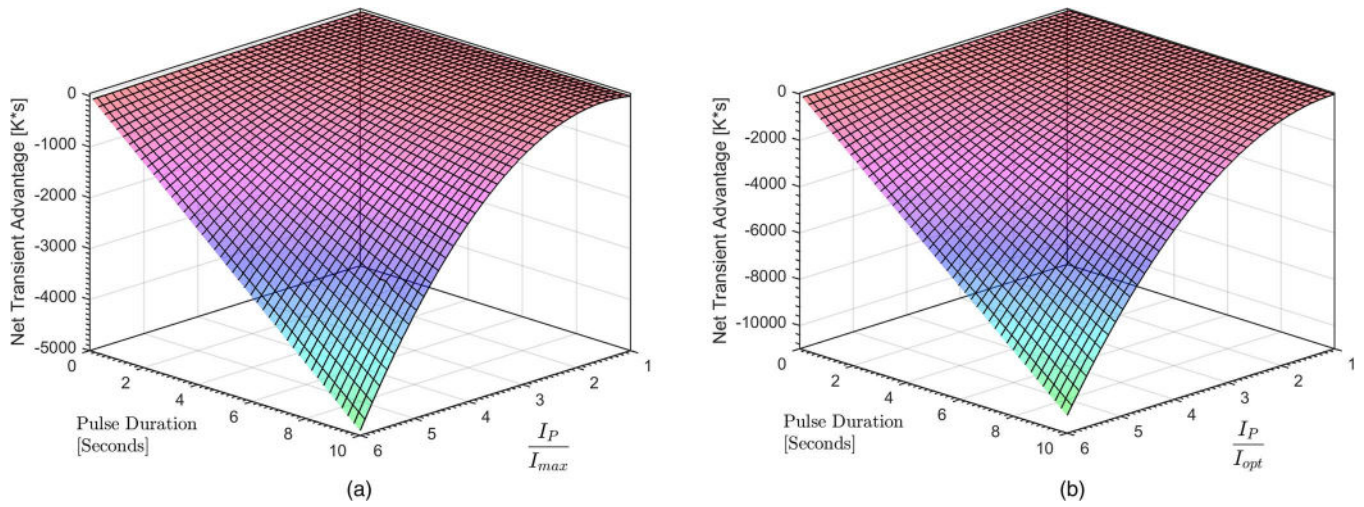


Figure 12. Net Transient Advantage - Full Study Range Surface (a) I_{max} (b) I_{opt} .

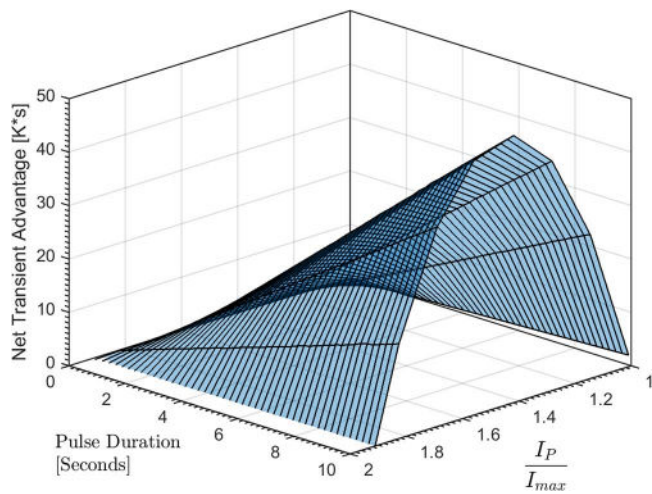


Figure 13. Net Transient Advantage - Advantage Portion, I_{max} Surface.

difference is a net advantage or net cooling and a negative difference is a net penalty or net heating. A net advantage indicates a net increase in Q_c for a transient pulse event over steady state operation. From Figure 12, for both I_{max} and I_{opt} operation, net transient advantage appears to approach zero. Upon closer inspection of the I_{max} operation surface and magnifying the scale, a net advantage is found. In Figure 13, this net transient advantage become more apparent. It is seen that I_{max} operation contains a net advantage between an I_P/I_{max} of 1 and 2. The net transient advantage also increases with pulse duration. Figure 14 shows the same data as the two surfaces in Figure 12. The figures are now viewed from the side and without surface. Figure 14 clearly shows the area where I_P/I_{max} creates a net transient advantage for I_{max} operation and the same I_P/I_{max} for I_{opt} creates a net transient penalty.

Conclusions

A single freestanding thermocouple was one-dimensionally modeled using electric-thermal analogies and solved for transient response using SPICE software. For the first time, response surfaces were

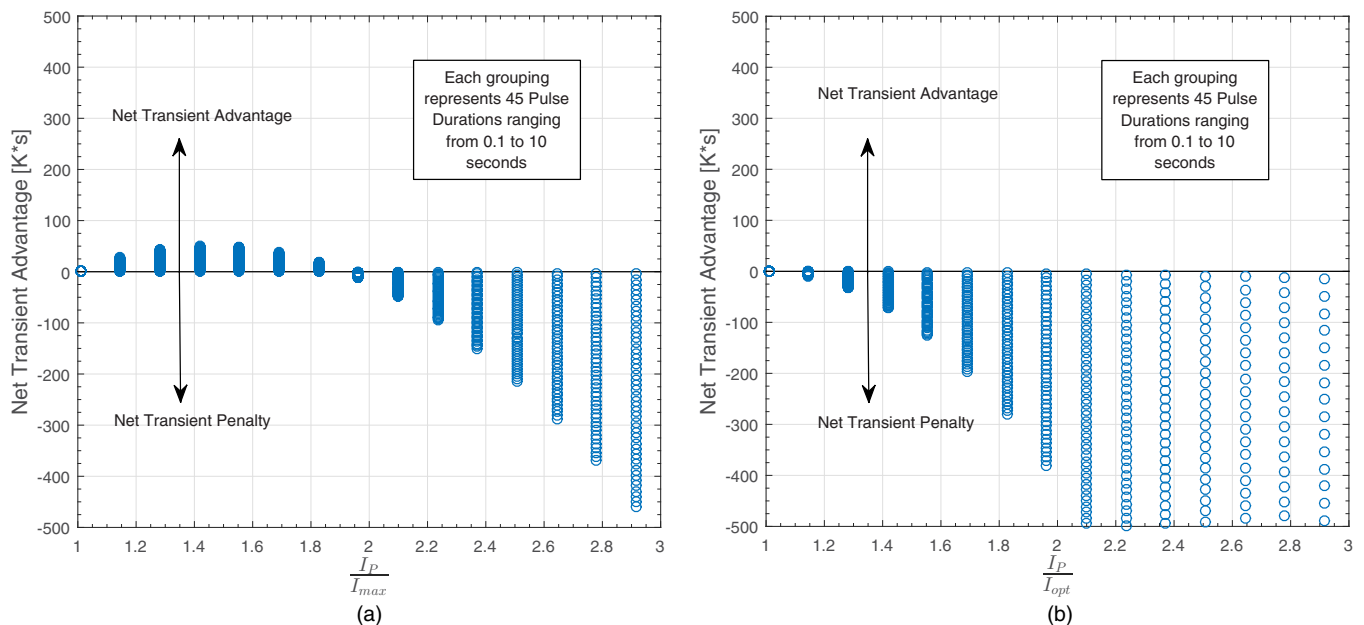


Figure 14. Net Transient Advantage - Partial Study Range, Alternate View (a) I_{max} (b) I_{opt} .

generated for the dependent variables relevant to Peltier pulse cooling. The results indicate the combination of pulse duration and pulse height that can maximize Net Transient Advantage for an Isosceles shaped current pulse. Additionally, a systematic parametric study to find optimums and trade-offs for each dependent variable was completed. For current pulses starting from I_{max} a Net Transient Advantage exists. When starting from I_{opt} , however, no Net Transient Advantage was found. For very low pulse heights a Transient Advantage can exist with no Transient Penalty. For pulse cooling, this fulfills the iNEMI roadmap goal of finding more effective and cost efficient ways of removing heat from electronic systems.

The results of the simulation indicate an optimum combination of pulse height and duration. This optimum combination varies depending upon the dependent variable. The method of using response surfaces is well-suited to comparing different pulse shapes on a common basis. It is possible that the optimum dependent variable values are the same for any given pulse shape, but occur at different combinations of independent variable for the same energy input. A future study could investigate other types of current pulse shapes.

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